Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S3	553	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/18 17:25
S22	621	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 17:25
S24	12	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive) not S23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 17:25
S23	609	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/18 17:27
S4	277	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive) and @ad<"20001130"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/18 17:33
S25	278	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 17:33
S26	128	(336/65 or 336/232).ccls. and (inductor or inductive) and (capacitor or capacitive) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 17:37
S18	299	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive or capacitance) and @ad<"20001130"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/18 17:39
S27	300	(257/531 or 257/528 or 257/532 or 257/534 or 257/774).ccls. and (inductor or inductive) and (capacitor or capacitive or capacitance) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 17:39

S28	11	(257/621).ccls. and (inductor or inductive) and (capacitor or capacitive) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 17:48
S16	972	semiconductor and (((via or plug or hole) near4 (entire or through)) with substrate) and ((inductor or inductive) with (capacitor or capacitive))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/18 17:56
S17	400	semiconductor and (((via or plug or hole) near4 (entire or through)) with substrate) and ((inductor or inductive) with (capacitor or capacitive)) and @ad<"20001130"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/18 17:56
S29	437	semiconductor and (((via or plug or hole) near4 (entire or through or inside or within)) with substrate) and ((inductor or inductive) with (capacitor or capacitive)) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 20:09
S30	838	semiconductor and (((via or plug or contact) near7 (entire or through or inside or within)) with substrate) and (inductor or inductive) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 20:10
S31	437	semiconductor and (((via or plug or hole) near4 (entire or through or inside or within)) with substrate) and ((inductor or inductive) with (capacitor or capacitive)) and @ad<"20001130"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 20:10
S32	528	semiconductor and (((via or plug or contact) near7 (entire or through or inside or within)) with substrate) and (inductor or inductive) and @ad<"20001130" not S31	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 20:11
S33	659	semiconductor and (((via or plug or contact or hole) near7 (entire or through or inside or within)) with substrate) and (inductor or inductive) and @ad<"20001130" not S31	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/18 23:12